

OPAx314 3MHz、低功耗、低噪声、RRIO、1.8V CMOS 运算放大器

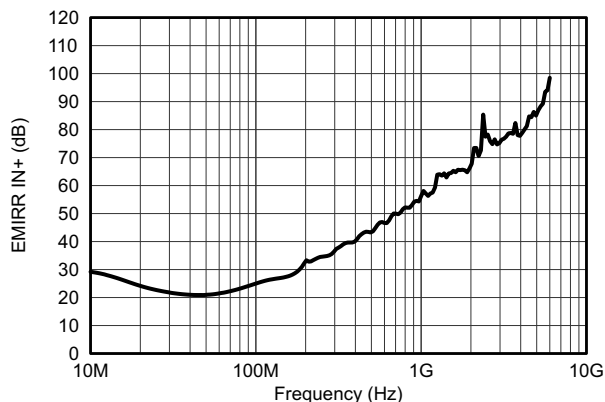
1 特性

- 低 I_Q : 150 μ A/通道
- 宽电源电压: 1.8V 至 5.5V
- 低噪声: 1kHz 下为 14nV/ $\sqrt{\text{Hz}}$
- 增益带宽: 3MHz
- 低输入偏置电流: 0.2pA
- 低偏移电压: 0.5mV
- 单位增益稳定
- 内部射频/电磁干扰 (RF/EMI) 滤波器
- 扩展温度范围:
-40°C 至 125°C

2 应用范围

- 电池供电仪器:
 - 消费类应用、工业应用、医疗应用
 - 笔记本电脑、便携式媒体播放器
- 光电二极管放大器
- 有源滤波器
- 远程感测
- 无线计量
- 手持测试设备

电磁干扰抑制比 (EMIRR) 与频率间的关系



3 说明

OPA314 系列单通道、双通道和四通道运算放大器是新一代低功耗、通用互补金属氧化物半导体 (CMOS) 放大器的典型代表。该器件系列将轨到轨输入和输出摆幅、低静态电流 (5 V_S 时的典型值为 150 μ A) 与 3MHz 高带宽和极低噪声 (1kHz 时为 14nV/ $\sqrt{\text{Hz}}$) 相结合, 广泛应用于 要求在成本和性能间达到良好平衡的 电池供电应用。低输入偏置电流支持 源阻抗高达兆欧级的 应用。

OPA314 器件采用稳健耐用的设计, 方便电路设计人员使用。该器件具有单位增益稳定的集成 RF/EMI 抑制滤波器, 在过驱条件下不会出现反相并且具有高静电放电 (ESD) 保护 (4kV 人体模型 (HBM))。

此类器件经过优化, 适合在 1.8V ($\pm 0.9V$) 至 5.5V ($\pm 2.75V$) 的低电压状态下工作并可在 -40°C 至 125°C 的完全扩展温度范围内额定运行。

OPA314 (单通道) 采用 SC70-5 和小外形尺寸晶体管 (SOT)23-5 封装。OPA2314 (双通道) 采用小外形尺寸 (SO)-8, 微型小外形尺寸 (MSOP)-8 和四方扁平无引线 (DFN)-8 封装。四通道 OPA4314 采用薄型小外形尺寸 (TSSOP)-14 封装。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
OPA314	SOT-23 (5)	2.90mm x 1.60mm
	SC70 (5)	2.00mm x 1.25mm
OPA2314	VSSOP (8)	3.00mm x 3.00mm
	SOIC (8)	4.90mm x 3.91mm
	VSON (8)	3.00mm x 3.00mm
OPA4314	薄型小外形尺寸封装 (TSSOP) (14)	5.00mm x 4.40mm

(1) 要了解所有可用封装, 请见数据表末尾的可订购产品附录。



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4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

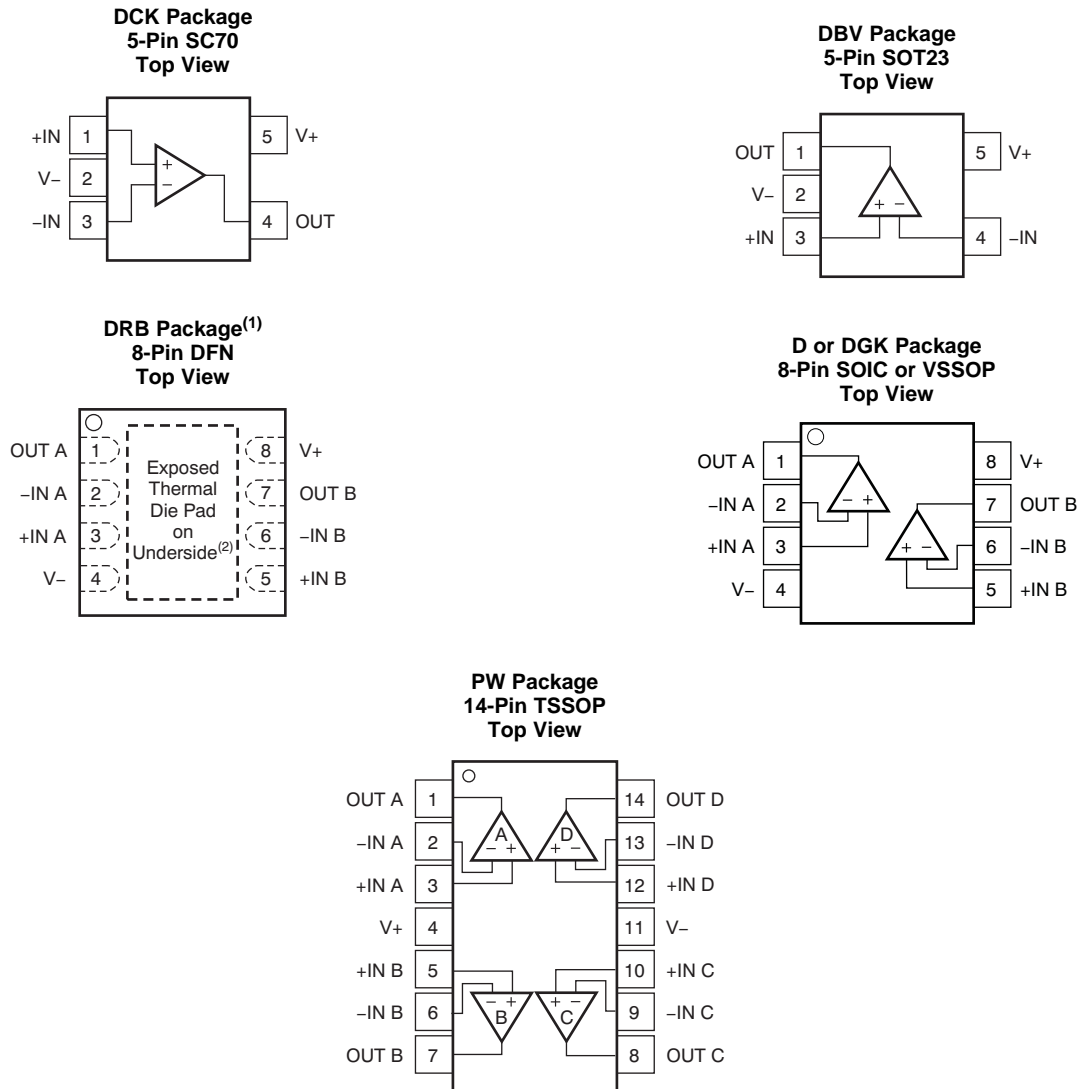
Changes from Revision F (April 2013) to Revision G	Page
• 已添加 ESD 额定值表，特性描述部分，器件功能模式，应用和实施部分，电源相关建议部分，布局部分，器件和文档支持部分以及机械、封装和可订购信息部分	1
• 已将修订历史记录移至第二页	1
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Changes from Revision E (September 2012) to Revision F	Page
• 已更改 文档标题（删除了“超值系列”）	1
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Changes from Revision D (March 2012) to Revision E	Page
• 已将“超值系列”添加至标题	1
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Changes from Revision C (February 2012) to Revision D	Page
• 已更改 将产品状态从混合状态改为生产数据	1
• 已删除 封装信息表中的底纹和脚注 2	1
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Changes from Revision B (December 2011) to Revision C	Page
• 已更改 第一项 特性 要点	1
• 已删除 封装信息表 OPA314 SOT23-5 行（DBV 封装）的底纹	1
• Added OPA2314, OPA4314 to first two Power Supply, <i>Quiescent current per amplifier</i> parameter rows in Electrical Characteristics table	8
• Added OPA314 Power Supply, <i>Quiescent current per amplifier</i> parameter row to Electrical Characteristics table	8

Changes from Revision A (August 2011) to Revision B

Page

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- 已删除 封装信息表 OPA2314 MSOP-8 行的底纹 1
-

5 Pin Configuration and Functions



(1) Pitch: 0.65 mm.

(2) Connect thermal pad to V-. Pad size: 1.8 mm × 1.5 mm.

Pin Functions: OPA314

NAME	PIN		I/O	DESCRIPTION
	DBV	DCK		
+IN	3	1	I	Noninverting input
-IN	4	3	I	Inverting input
OUT	1	4	O	Output
V+	5	5	—	Positive (highest) supply
V-	2	2	—	Negative (lowest) supply

Pin Functions: OPA2314

NAME	PIN			I/O	DESCRIPTION
	DRB	DGK	D		
+IN A	3	3	3	I	Noninverting input
+IN B	5	5	5	I	Noninverting input
–IN A	2	2	2	I	Inverting input
–IN B	6	6	6	I	Inverting input
OUT A	1	1	1	O	Output
OUT B	7	7	7	O	Output
V+	8	8	8	—	Positive (highest) supply
V–	4	4	4	—	Negative (lowest) supply

Pin Functions: OPA4314

NAME	PIN		I/O	DESCRIPTION
	NO.			
+IN A	3		I	Noninverting input
+IN B	5		I	Noninverting input
+IN C	10		I	Noninverting input
+IN D	12		I	Noninverting input
–IN A	2		I	Inverting input
–IN B	6		I	Inverting input
–IN C	9		I	Inverting input
–IN D	13		I	Inverting input
OUT A	1		O	Output
OUT B	7		O	Output
OUT C	8		O	Output
OUT D	14		O	Output
V+	4		—	Positive (highest) supply
V–	11		—	Negative (lowest) supply

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range, unless otherwise noted.⁽¹⁾

		MIN	MAX	UNIT
Supply voltage		7		V
Signal input terminals	Voltage ⁽²⁾	(V–) – 0.5	(V+) + 0.5	V
	Current ⁽²⁾	–10	10	mA
Output short-circuit ⁽³⁾		Continuous		mA
Operating temperature, T _A		–40	150	°C
Junction temperature, T _J				°C
Storage temperature, T _{stg}		–65	150	°C

- Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.
- Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails should be current limited to 10 mA or less.
- Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	
	Machine model (MM)	±200	

- JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _S	Supply voltage	1.8 (±0.9)		5.5 (±2.75)	V
T _A	Ambient operating temperature	–40		125	°C

6.4 Thermal Information: OPA314

THERMAL METRIC ⁽¹⁾	OPA314			UNIT	
	DBV (SOT23)	DCK (SC70)	DRL (SOT553)		
	5 PINS	5 PINS	5 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	228.5	281.4	208.1	°C/W
R _{θJC(top)}	Junction-to-case(top) thermal resistance	99.1	91.6	0.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	54.6	59.6	42.4	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	7.7	1.5	0.5	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	53.8	58.8	42.2	°C/W

- For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Thermal Information: OPA2314

THERMAL METRIC ⁽¹⁾		OPA2314			UNIT
		D (SO)	DGK (MSOP)	DRB (DFN)	
		8 PINS	8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	138.4	191.2	53.8	°C/W
R _{θJC(top)}	Junction-to-case(top) thermal resistance	89.5	61.9	69.2	°C/W
R _{θJB}	Junction-to-board thermal resistance	78.6	111.9	20.1	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	29.9	5.1	3.8	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	78.1	110.2	11.6	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.6 Thermal Information: OPA4314

THERMAL METRIC ⁽¹⁾		OPA4314		UNIT
		D (SOIC)	PW (TSSOP)	
		14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	93.2	121	°C/W
R _{θJC(top)}	Junction-to-case(top) thermal resistance	51.8	49.4	°C/W
R _{θJB}	Junction-to-board thermal resistance	49.4	62.8	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	13.5	5.9	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	42.2	62.2	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.7 Electrical Characteristics

V_S = 1.8 V to 5.5 V; At T_A = 25 °C, R_L = 10 kΩ connected to V_S/2, V_{CM} = V_S/2, and V_{OUT} = V_S/2, unless otherwise noted.⁽¹⁾

PARAMETER	TEST CONDITIONS	T _A = 25 °C			T _A = -40°C to 125°C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
OFFSET VOLTAGE								
V _{OS}	Input offset voltage	V _{CM} = (V _{S+}) - 1.3 V		0.5	2.5			mV
dV _{OS} /dT	vs Temperature					1		μV/°C
PSRR	vs power supply	V _{CM} = (V _{S+}) - 1.3 V		78	92			dB
	Over temperature					74		dB
	Channel separation, DC	At DC		10				μV/V
INPUT VOLTAGE RANGE								
V _{CM}	Common-mode voltage range			(V ₋) - 0.2	(V ₊) + 0.2			V
CMRR	Common-mode rejection ratio	V _S = 1.8 V to 5.5 V, (V _{S-}) - 0.2 V < V _{CM} < (V _{S+}) - 1.3 V		75	96			dB
		V _S = 5.5 V, V _{CM} = -0.2 V to 5.7 V ⁽²⁾		66	80			dB
	Over temperature	V _S = 1.8 V, (V _{S-}) - 0.2 V < V _{CM} < (V _{S+}) - 1.3 V				70	86	dB
		V _S = 5.5 V, (V _{S-}) - 0.2 V < V _{CM} < (V _{S+}) - 1.3 V				73	90	dB
		V _S = 5.5 V, V _{CM} = -0.2 V to 5.7 V ⁽²⁾				60		dB
INPUT BIAS CURRENT								
I _B	Input bias current			±0.2	±10			pA
	Over temperature						±600	pA
I _{OS}	Input offset current			±0.2	±10			pA
	Over temperature						±600	pA
NOISE								
	Input voltage noise (peak-to-peak)	f = 0.1 Hz to 10 Hz		5				μV _{PP}

(1) Parameters with minimum or maximum specification limits are 100% production tested at +25°C, unless otherwise noted. Over temperature limits are based on characterization and statistical analysis.

(2) Specified by design and characterization; not production tested.

Electrical Characteristics (continued)
 $V_S = 1.8\text{ V to }5.5\text{ V}$; At $T_A = 25\text{ }^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.⁽¹⁾

PARAMETER		TEST CONDITIONS	$T_A = 25\text{ }^\circ\text{C}$			$T_A = -40\text{ }^\circ\text{C to }125\text{ }^\circ\text{C}$			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
e_n	Input voltage noise density	$f = 10\text{ kHz}$		13					nV/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		14					nV/ $\sqrt{\text{Hz}}$
i_n	Input current noise density	$f = 1\text{ kHz}$		5					fA/ $\sqrt{\text{Hz}}$
INPUT CAPACITANCE									
C_{IN}	Differential	$V_S = 5\text{ V}$		1					pF
	Common-mode	$V_S = 5\text{ V}$		5					pF
OPEN-LOOP GAIN									
A_{OL}	Open-loop voltage gain	$V_S = 1.8\text{ V}, 0.2\text{ V} < V_O < (V+) - 0.2\text{ V}, R_L = 10\text{ k}\Omega$	90	115					dB
		$V_S = 5.5\text{ V}, 0.2\text{ V} < V_O < (V+) - 0.2\text{ V}, R_L = 10\text{ k}\Omega$	100	128					dB
		$V_S = 1.8\text{ V}, 0.5\text{ V} < V_O < (V+) - 0.5\text{ V}, R_L = 2\text{ k}\Omega^{(2)}$	90	100					dB
		$V_S = 5.5\text{ V}, 0.5\text{ V} < V_O < (V+) - 0.5\text{ V}, R_L = 2\text{ k}\Omega^{(2)}$	94	110					dB
Over temperature		$V_S = 5.5\text{ V}, 0.2\text{ V} < V_O < (V+) - 0.2\text{ V}, R_L = 10\text{ k}\Omega$				90	110		dB
		$V_S = 5.5\text{ V}, 0.5\text{ V} < V_O < (V+) - 0.2\text{ V}, R_L = 2\text{ k}\Omega$					100		dB
Phase margin		$V_S = 5\text{ V}, G = 1, R_L = 10\text{ k}\Omega$		65					°
FREQUENCY RESPONSE									
GBW	Gain-bandwidth product	$V_S = 1.8\text{ V}, R_L = 10\text{ k}\Omega, C_L = 10\text{ pF}$		2.7					MHz
		$V_S = 5\text{ V}, R_L = 10\text{ k}\Omega, C_L = 10\text{ pF}$		3					MHz
SR	Slew rate ⁽³⁾	$V_S = 5\text{ V}, G = 1$		1.5					V/ μs
t_s	Settling time	To 0.1%, $V_S = 5\text{ V}, 2\text{-V step}, G = 1$		2.3					μs
		To 0.01%, $V_S = 5\text{ V}, 2\text{-V step}, G = 1$		3.1					μs
Overload recovery time		$V_S = 5\text{ V}, V_{IN} \times \text{Gain} > V_S$		5.2					μs
THD+N	Total harmonic distortion + noise ⁽⁴⁾	$V_S = 5\text{ V}, V_O = 1\text{ V}_{RMS}, G = +1, f = 1\text{ kHz}, R_L = 10\text{ k}\Omega$		0.001%					
OUTPUT									
V_O	Voltage output swing from supply rails	$V_S = 1.8\text{ V}, R_L = 10\text{ k}\Omega$		5	15				mV
		$V_S = 5.5\text{ V}, R_L = 10\text{ k}\Omega$		5	20				mV
		$V_S = 1.8\text{ V}, R_L = 2\text{ k}\Omega$		15	30				mV
		$V_S = 5.5\text{ V}, R_L = 2\text{ k}\Omega$		22	40				mV
Over temperature		$V_S = 5.5\text{ V}, R_L = 10\text{ k}\Omega$						30	mV
		$V_S = 5.5\text{ V}, R_L = 2\text{ k}\Omega$					60		mV
I_{SC}	Short-circuit current	$V_S = 5\text{ V}$		± 20					mA
R_O	Open-loop output impedance	$V_S = 5.5\text{ V}, f = 100\text{ Hz}$		570					Ω
POWER SUPPLY									
V_S	Specified voltage range		1.8		5.5				V
I_Q	Quiescent current per amplifier	OPA314, OPA2314, OPA4314, $V_S = 1.8\text{ V}, I_O = 0\text{ mA}$		130	180				μA
		OPA2314, OPA4314, $V_S = 5\text{ V}, I_O = 0\text{ mA}$		150	190				μA
		OPA314, $V_S = 5\text{ V}, I_O = 0\text{ mA}$		150	210				μA
Over temperature		$V_S = 5\text{ V}, I_O = 0\text{ mA}$					220		μA
Power-on time		$V_S = 0\text{ V to }5\text{ V}, \text{ to }90\% I_Q \text{ level}$		44					μs
TEMPERATURE									
Specified range			-40		125				$^\circ\text{C}$
Operating range			-40		150				$^\circ\text{C}$

(3) Signifies the slower value of the positive or negative slew rate.

(4) Third-order filter; bandwidth = 80 kHz at -3 dB.

Electrical Characteristics (continued)

$V_S = 1.8\text{ V to }5.5\text{ V}$; At $T_A = 25\text{ }^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.⁽¹⁾

PARAMETER	TEST CONDITIONS	$T_A = 25\text{ }^\circ\text{C}$			$T_A = -40\text{ }^\circ\text{C to }125\text{ }^\circ\text{C}$			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
Storage range		-65		150				$^\circ\text{C}$

6.8 Typical Characteristics

Table 1. Characteristic Performance Measurements

TITLE	FIGURE
Open-Loop Gain and Phase vs Frequency	Figure 1
Open-Loop Gain vs Temperature	Figure 2
Quiescent Current vs Supply Voltage	Figure 3
Quiescent Current vs Temperature	Figure 4
Offset Voltage Production Distribution	Figure 5
Offset Voltage Drift Distribution	Figure 6
Offset Voltage vs Common-Mode Voltage (Maximum Supply)	Figure 7
Offset Voltage vs Temperature	Figure 8
CMRR and PSRR vs Frequency (RTI)	Figure 9
CMRR and PSRR vs Temperature	Figure 10
0.1-Hz to 10-Hz Input Voltage Noise (5.5 V)	Figure 11
Input Voltage Noise Spectral Density vs Frequency (1.8 V, 5.5 V)	Figure 12
Input Voltage Noise vs Common-Mode Voltage (5.5 V)	Figure 13
Input Bias and Offset Current vs Temperature	Figure 14
Open-Loop Output Impedance vs Frequency	Figure 15
Maximum Output Voltage vs Frequency and Supply Voltage	Figure 16
Output Voltage Swing vs Output Current (over Temperature)	Figure 17
Closed-Loop Gain vs Frequency, $G = 1, -1, 10$ (1.8 V)	Figure 18
Closed-Loop Gain vs Frequency, $G = 1, -1, 10$ (5.5 V)	Figure 19
Small-Signal Overshoot vs Load Capacitance	Figure 20
Small-Signal Step Response, Noninverting (1.8 V)	Figure 21
Small-Signal Step Response, Noninverting (5.5 V)	Figure 22
Large-Signal Step Response, Noninverting (1.8 V)	Figure 23
Large-Signal Step Response, Noninverting (5.5 V)	Figure 24
Positive Overload Recovery	Figure 25
Negative Overload Recovery	Figure 26
No Phase Reversal	Figure 27
Channel Separation vs Frequency (Dual)	Figure 28
THD+N vs Amplitude ($G = 1, 2\text{ k}\Omega, 10\text{ k}\Omega$)	Figure 29
THD+N vs Amplitude ($G = -1, 2\text{ k}\Omega, 10\text{ k}\Omega$)	Figure 30
THD+N vs Frequency ($0.5\text{ V}_{RMS}, G = +1, 2\text{ k}\Omega, 10\text{ k}\Omega$)	Figure 31
EMIRR	Figure 32

OPA314, OPA2314, OPA4314

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At $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_{S/2}$, $V_{CM} = V_{S/2}$, and $V_{OUT} = V_{S/2}$, unless otherwise noted.

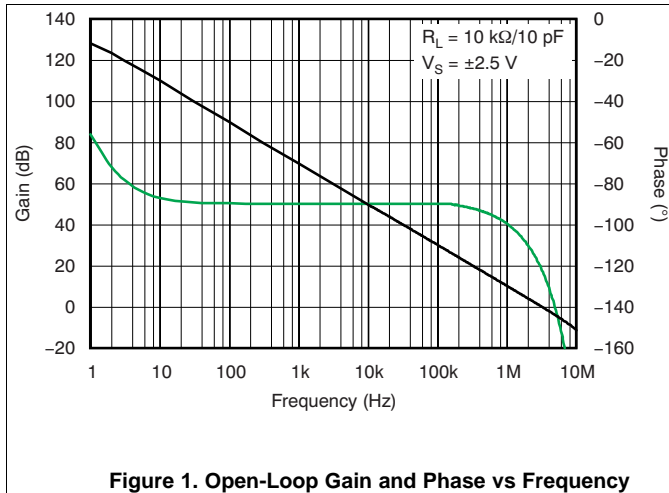


Figure 1. Open-Loop Gain and Phase vs Frequency

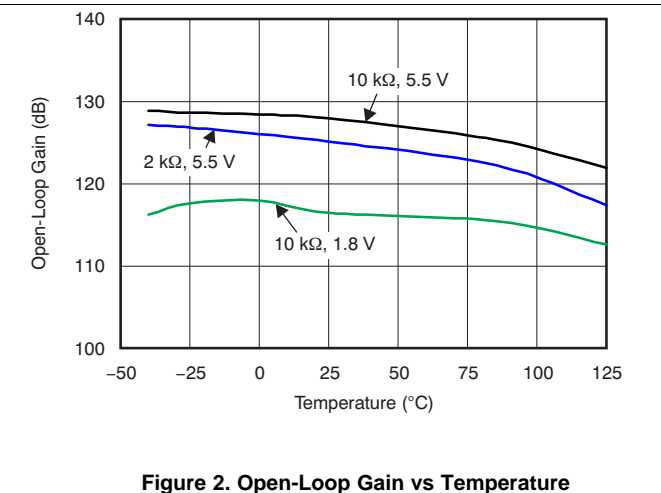


Figure 2. Open-Loop Gain vs Temperature

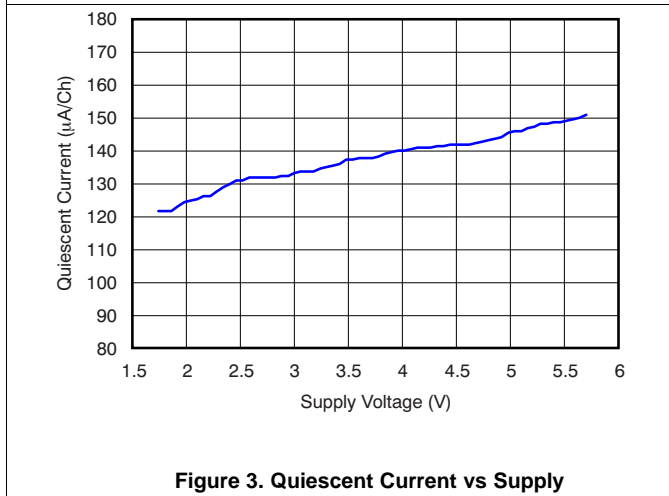


Figure 3. Quiescent Current vs Supply

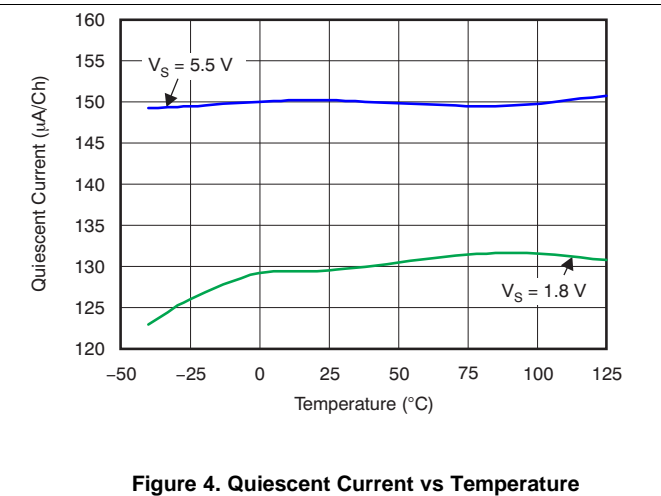


Figure 4. Quiescent Current vs Temperature

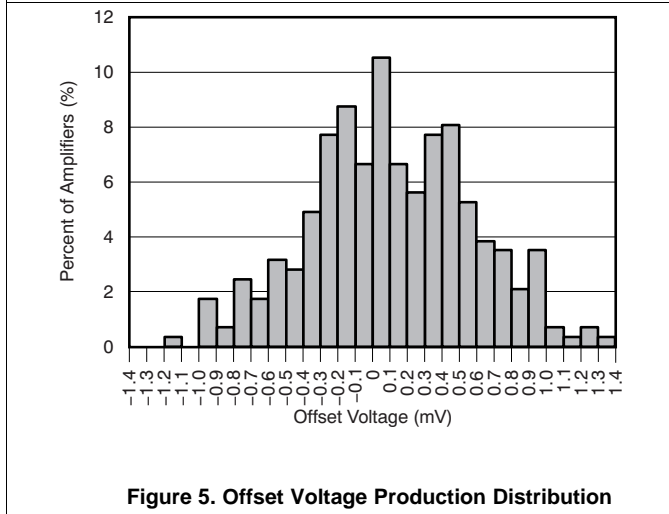


Figure 5. Offset Voltage Production Distribution

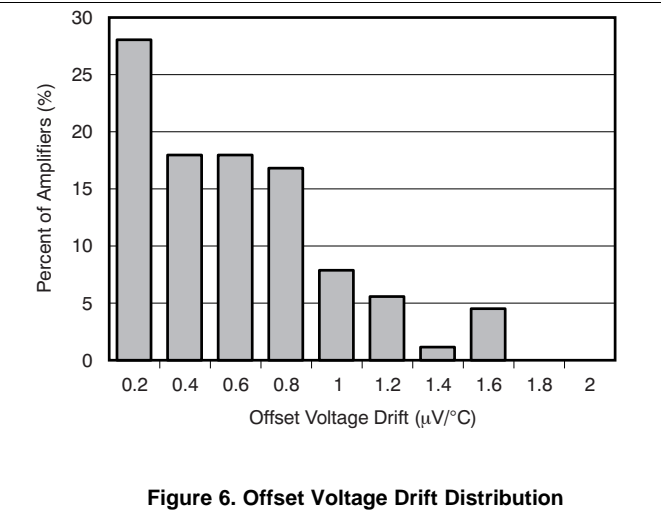


Figure 6. Offset Voltage Drift Distribution

At $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

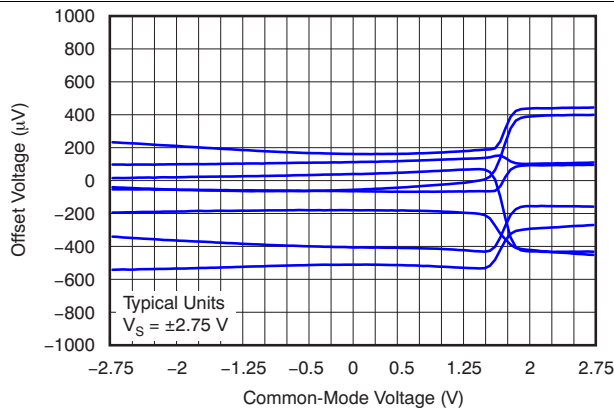


Figure 7. Offset Voltage vs Common-Mode Voltage

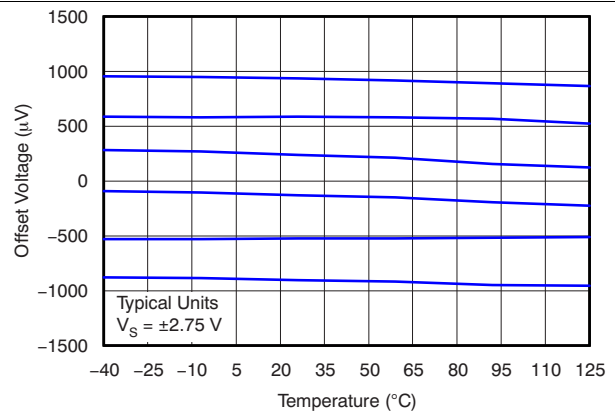


Figure 8. Offset Voltage vs Temperature

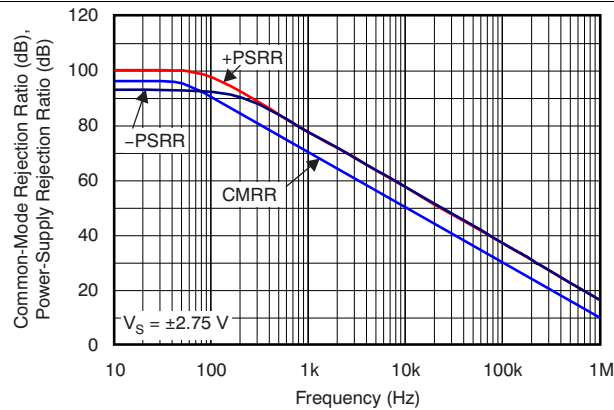


Figure 9. CMRR and PSRR vs Frequency (Referred-to-Input)

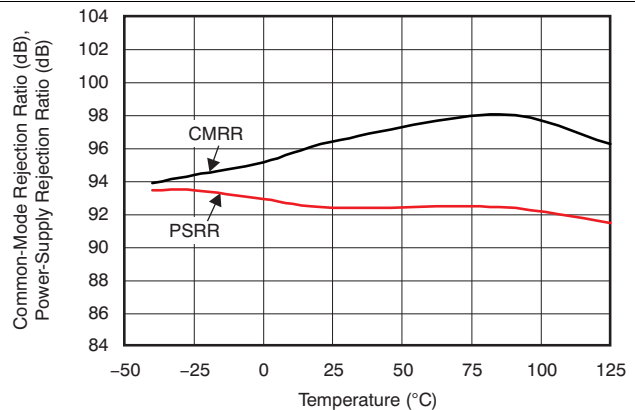


Figure 10. CMRR and PSRR vs Temperature

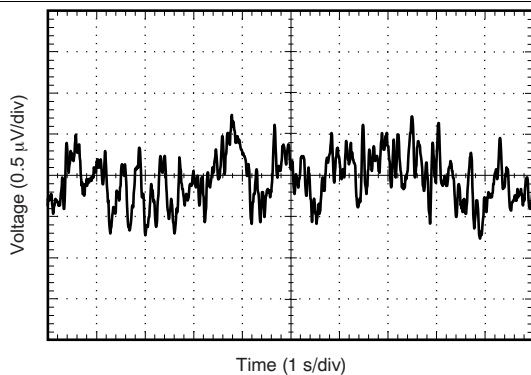


Figure 11. 0.1-Hz to 10-Hz Input Voltage Noise

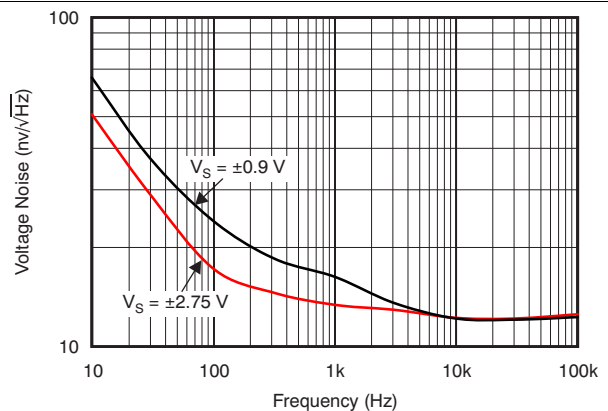


Figure 12. Input Voltage Noise Spectral Density vs Frequency

At $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

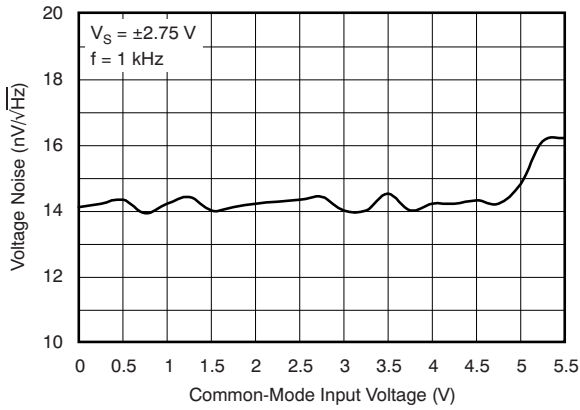


Figure 13. Voltage Noise vs Common-Mode Voltage

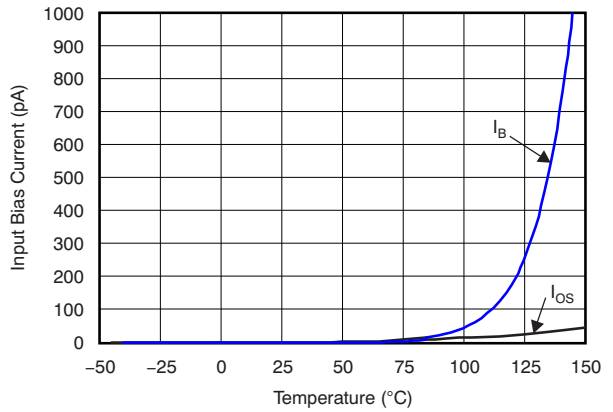


Figure 14. Input Bias and Offset Current vs Temperature

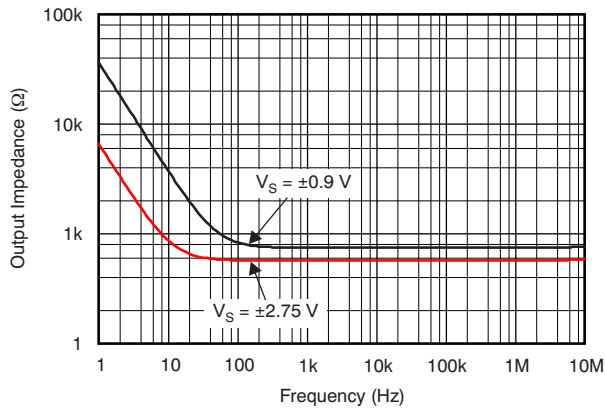


Figure 15. Open-Loop Output Impedance vs Frequency

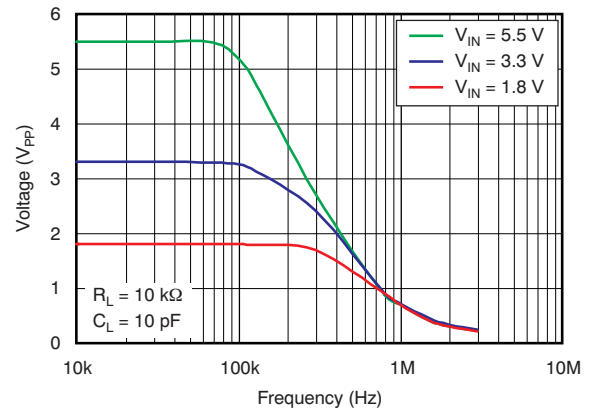


Figure 16. Maximum Output Voltage vs Frequency and Supply Voltage

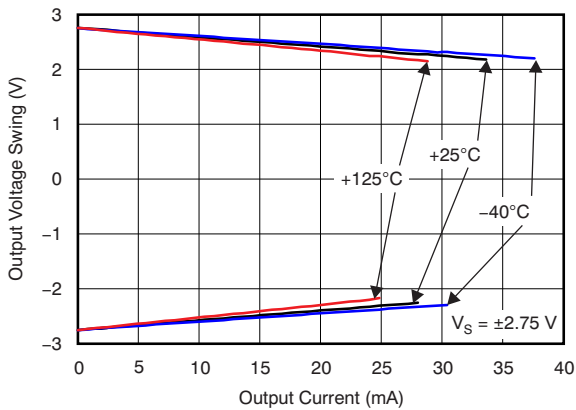


Figure 17. Output Voltage Swing vs Output Current (Over Temperature)

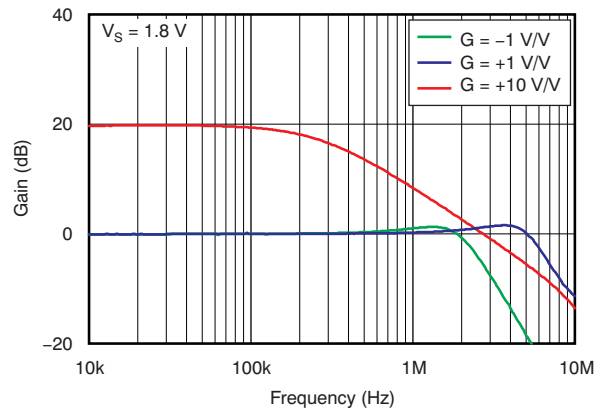


Figure 18. Closed-Loop Gain vs Frequency

At $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

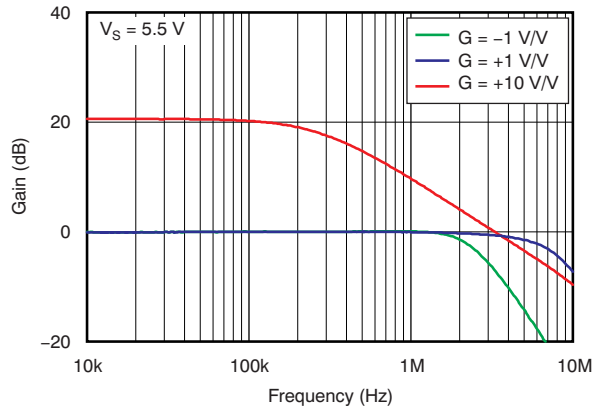


Figure 19. Closed-Loop Gain vs Frequency

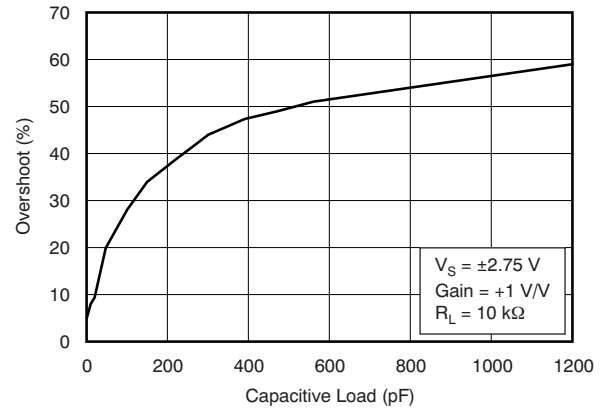


Figure 20. Small-Signal Overshoot vs Load Capacitance

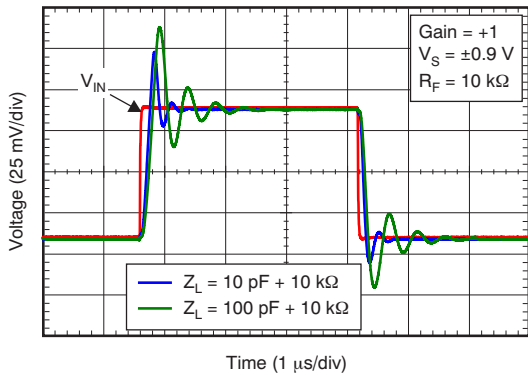


Figure 21. Small-Signal Pulse Response (Noninverting)

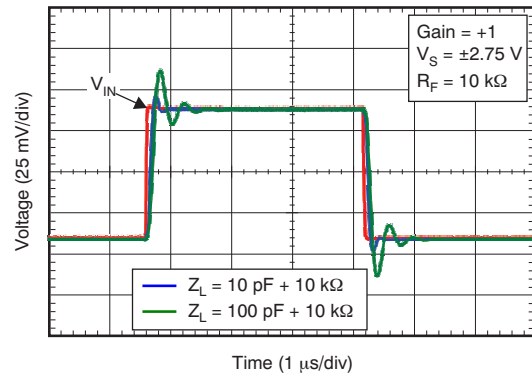


Figure 22. Small-Signal Pulse Response (Inverting)

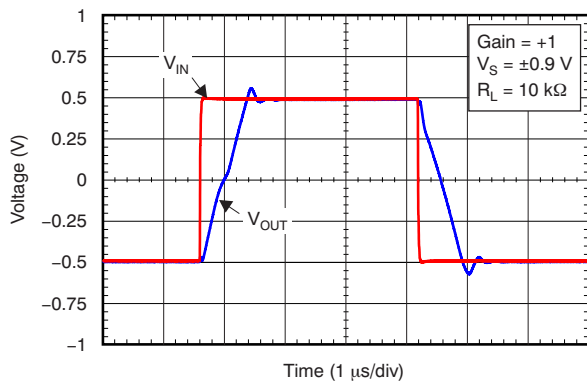


Figure 23. Large-Signal Pulse Response (Noninverting)

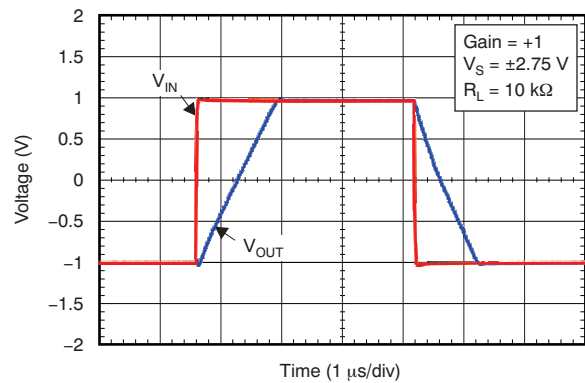


Figure 24. Large-Signal Pulse Response (Inverting)

At $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.

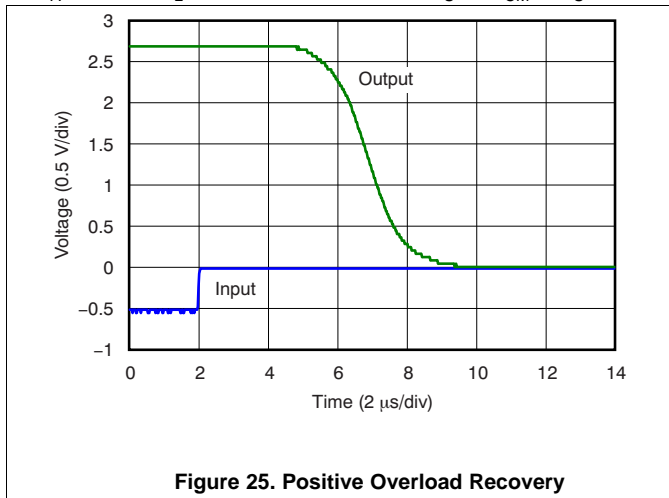


Figure 25. Positive Overload Recovery

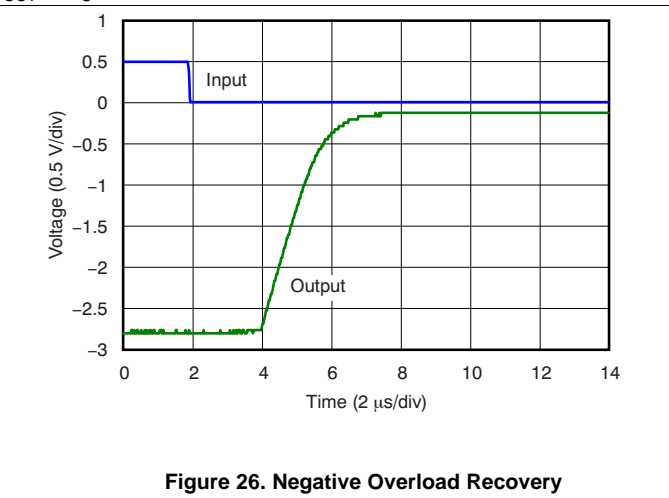


Figure 26. Negative Overload Recovery

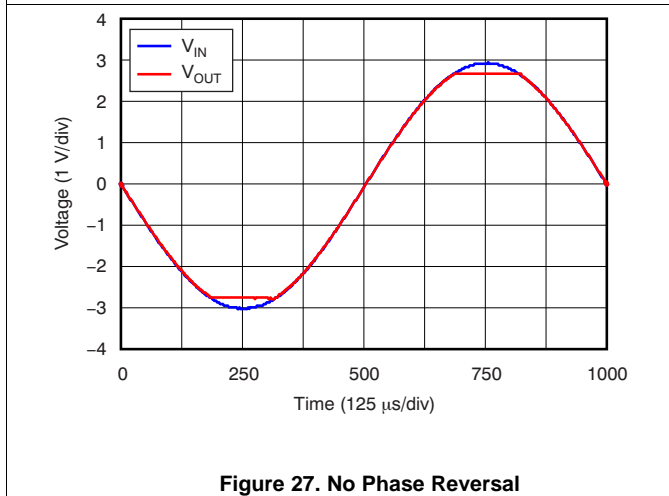


Figure 27. No Phase Reversal

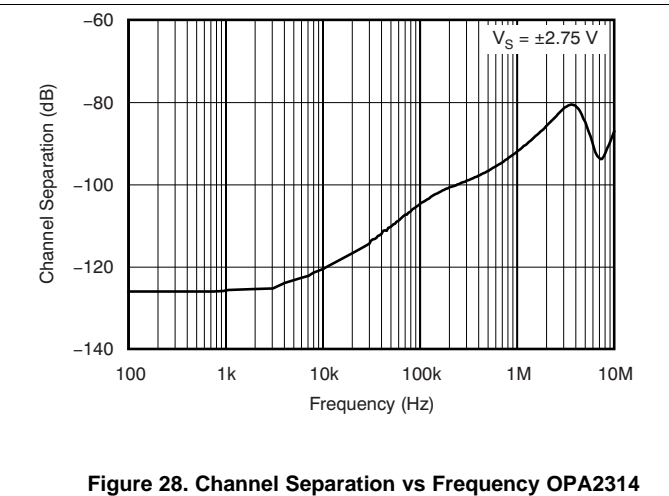


Figure 28. Channel Separation vs Frequency OPA2314

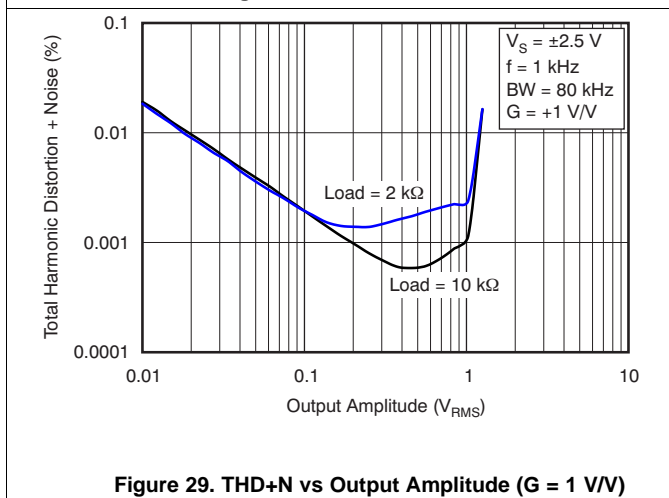


Figure 29. THD+N vs Output Amplitude ($G = 1\text{ V/V}$)

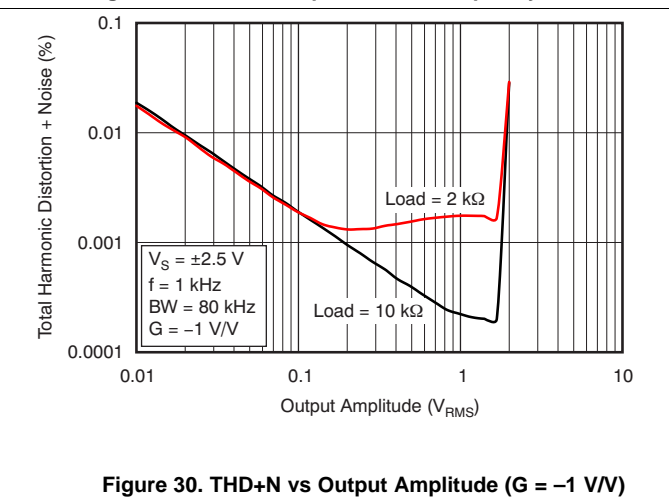
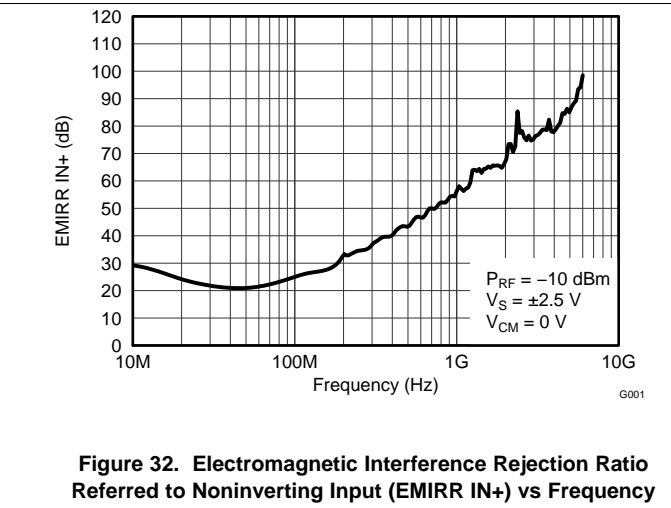
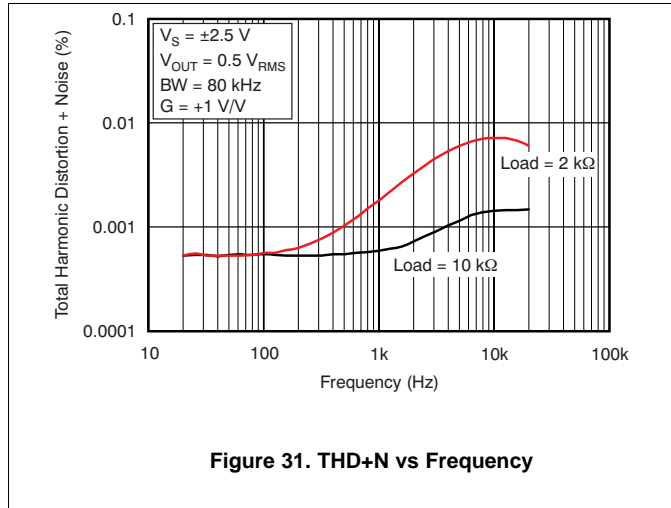


Figure 30. THD+N vs Output Amplitude ($G = -1\text{ V/V}$)

At $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $V_{CM} = V_S/2$, and $V_{OUT} = V_S/2$, unless otherwise noted.



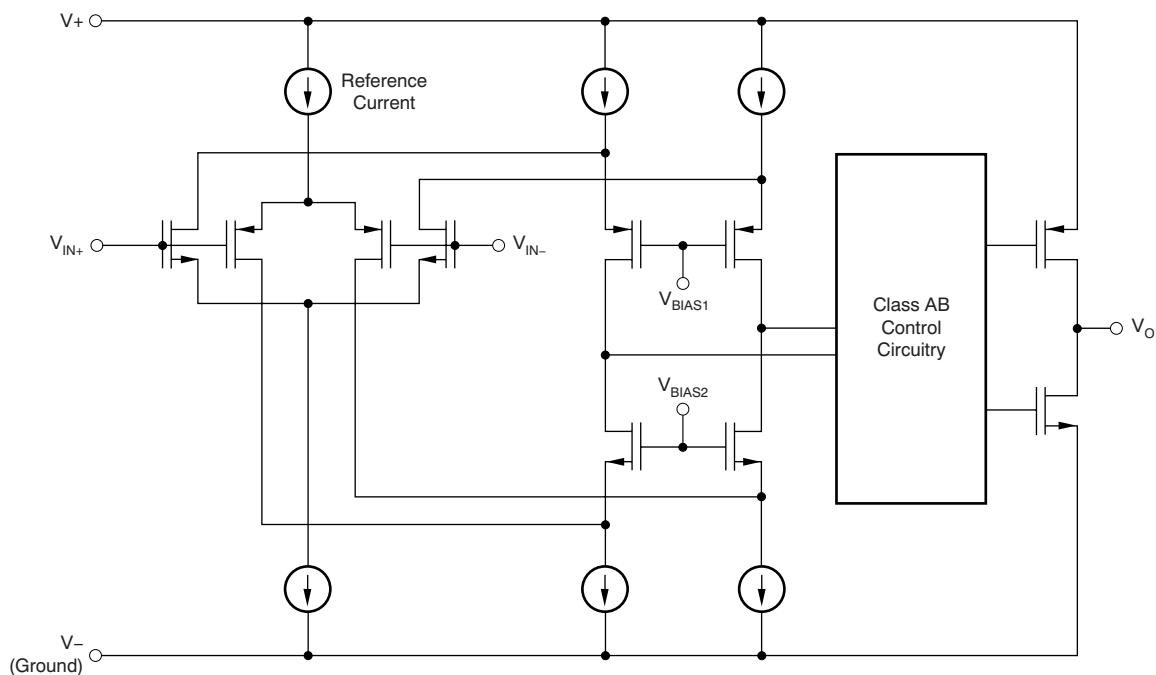
7 Detailed Description

7.1 Overview

The OPA314 is a family of low-power, rail-to-rail input and output operational amplifiers specifically designed for portable applications. These devices operate from 1.8 V to 5.5 V, are unity-gain stable, and suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving $\leq 10\text{-k}\Omega$ loads connected to any point between $V+$ and ground. The input common-mode voltage range includes both rails, and allows the OPA314 series to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes them ideal for driving sampling analog-to-digital converters (ADCs).

The OPA314 features 3-MHz bandwidth and $1.5\text{-V}/\mu\text{s}$ slew rate with only $150\text{-}\mu\text{A}$ supply current per channel, providing good AC performance at very low power consumption. DC applications are also well served with a very low input noise voltage of $14\text{ nV}/\sqrt{\text{Hz}}$ at 1 kHz, low input bias current (0.2 pA), and an input offset voltage of 0.5 mV (typical).

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Operating Voltage

The OPA314 series operational amplifiers are fully specified and ensured for operation from 1.8 V to 5.5 V. In addition, many specifications apply from -40°C to 125°C . Parameters that vary significantly with operating voltages or temperature are shown in the *Typical Characteristics* graphs. Power-supply pins should be bypassed with $0.01\text{-}\mu\text{F}$ ceramic capacitors.

Feature Description (continued)

7.3.2 Rail-to-Rail Input

The input common-mode voltage range of the OPA314 series extends 200 mV beyond the supply rails. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as shown in Figure 33. The N-channel pair is active for input voltages close to the positive rail, typically $(V+) - 1.3\text{ V}$ to 200 mV above the positive supply, while the P-channel pair is on for inputs from 200 mV below the negative supply to approximately $(V+) - 1.3\text{ V}$. There is a small transition region, typically $(V+) - 1.4\text{ V}$ to $(V+) - 1.2\text{ V}$, in which both pairs are on. This 200-mV transition region can vary up to 300 mV with process variation. Thus, the transition region (both stages on) can range from $(V+) - 1.7\text{ V}$ to $(V+) - 1.5\text{ V}$ on the low end, up to $(V+) - 1.1\text{ V}$ to $(V+) - 0.9\text{ V}$ on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD may be degraded compared to device operation outside this region.

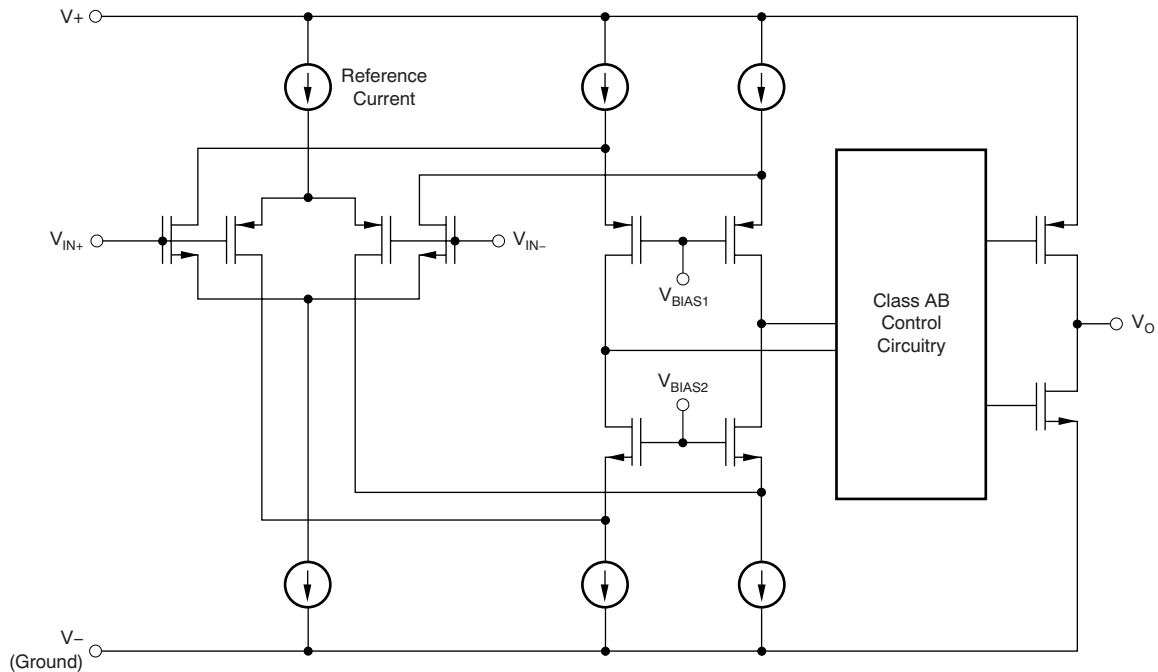


Figure 33. Simplified Schematic

7.3.3 Input and ESD Protection

The OPA314 family incorporates internal electrostatic discharge (ESD) protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes also provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA as stated in the [Absolute Maximum Ratings](#). Figure 34 shows how a series input resistor may be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and its value should be kept to a minimum in noise-sensitive applications.

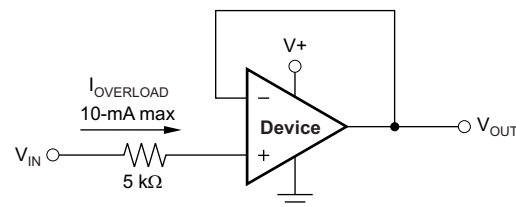


Figure 34. Input Current Protection

Feature Description (continued)

7.3.4 Common-Mode Rejection Ratio (CMRR)

CMRR for the OPA314 is specified in several ways so the best match for a given application may be used; see the [Electrical Characteristics](#). First, the CMRR of the device in the common-mode range below the transition region [$V_{CM} < (V+) - 1.3\text{ V}$] is given. This specification is the best indicator of the capability of the device when the application requires use of one of the differential input pairs. Second, the CMRR over the entire common-mode range is specified at ($V_{CM} = -0.2\text{ V}$ to 5.7 V). This last value includes the variations seen through the transition region (see [Figure 7](#)).

7.3.5 EMI Susceptibility and Input Filtering

Operational amplifiers vary with regard to the susceptibility of the device to electromagnetic interference (EMI). If conducted EMI enters the operational amplifier, the DC offset observed at the amplifier output may shift from its nominal value while EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. While all operational amplifier pin functions can be affected by EMI, the signal input pins are likely to be the most susceptible. The OPA314 operational amplifier family incorporate an internal input low-pass filter that reduces the amplifiers response to EMI. Both common-mode and differential mode filtering are provided by this filter. The filter is designed for a cutoff frequency of approximately 80 MHz (-3 dB), with a roll-off of 20 dB per decade.

Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. The EMI rejection ratio (EMIRR) metric allows operational amplifiers to be directly compared by the EMI immunity. [Figure 32](#) illustrates the results of this testing on the OPAX314. Detailed information can also be found in the application report, *EMI Rejection Ratio of Operational Amplifiers* ([SBOA128](#)), available for download from www.ti.com.

7.3.6 Rail-to-Rail Output

Designed as a micro-power, low-noise operational amplifier, the OPA314 delivers a robust output drive capability. A class AB output stage with common-source transistors is used to achieve full rail-to-rail output swing capability. For resistive loads up to 10 k Ω , the output swings typically to within 5 mV of either supply rail regardless of the power-supply voltage applied. Different load conditions change the ability of the amplifier to swing close to the rails; refer to [Figure 17](#).

7.3.7 Capacitive Load and Stability

The OPA314 is designed to be used in applications where driving a capacitive load is required. As with all operational amplifiers, there may be specific instances where the OPA314 can become unstable. The particular operational amplifiers circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation. An operational amplifier in the unity-gain ($+1\text{-V/V}$) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the operational amplifier output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. When operating in the unity-gain configuration, the OPA314 remains stable with a pure capacitive load up to approximately 1 nF. The equivalent series resistance (ESR) of some very large capacitors (C_L greater than 1 μF) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains. See [Figure 20](#).

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor, typically 10 Ω to 20 Ω , in series with the output, as shown in [Figure 35](#). This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique, however, is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.

Feature Description (continued)

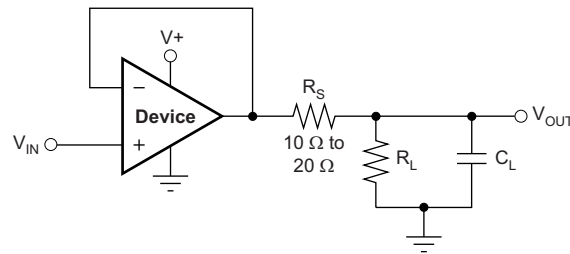


Figure 35. Improving Capacitive Load Drive

7.4 Device Functional Modes

The OPA2314 device is powered on when the supply is connected. The device can be operated as a single-supply operational amplifier or a dual-supply amplifier, depending on the application.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

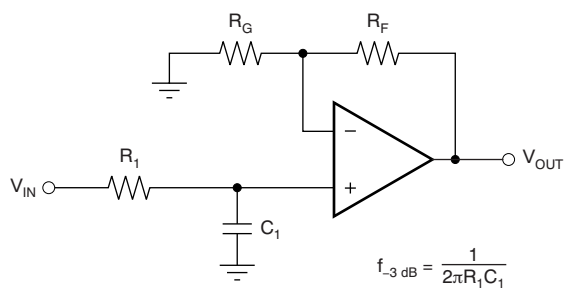
8.1 Application Information

The OPA2314 device is a low-power, rail-to-rail input and output operational amplifier specifically designed for portable applications. The device operates from 1.8 V to 5.5 V, is unity-gain stable, and suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving $\leq 10\text{-k}\Omega$ loads connected to any point between $V+$ and ground. The input common-mode voltage range includes both rails, and allows the OPA2314 device to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes the device ideal for driving sampling analog-to-digital converters (ADCs).

The OPA2314 device features a 3-MHz bandwidth and 1.5-V/ μs slew rate with only 150- μA supply current per channel, providing good AC performance at very low power consumption. DC applications are also well served with a very-low input noise voltage of 14 nV/ $\sqrt{\text{Hz}}$ at 1 kHz, low-input bias current (0.2 pA), and an input offset voltage of 0.5 mV (typical).

8.1.1 General Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier, as Figure 36 shows.



$$\frac{V_{\text{OUT}}}{V_{\text{IN}}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1 C_1}\right)$$

Figure 36. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as Figure 37 shows. For best results, the amplifier should have a bandwidth that is eight to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in phase shift of the amplifier.

Application Information (continued)

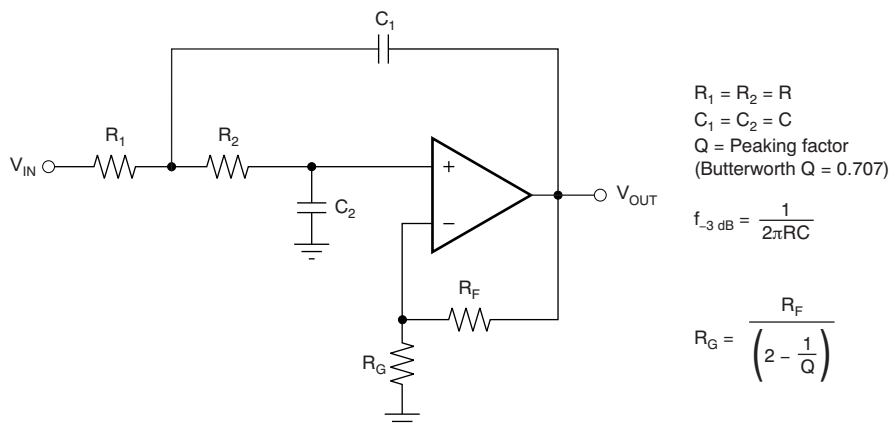


Figure 37. Two-Pole Low-Pass Sallen-Key Filter

8.1.2 Capacitive Load and Stability

The OPA2314 device is designed to be used in applications where driving a capacitive load is required. As with all op-amps, specific instances can occur where the OPA2314 device can become unstable. The particular op-amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation. An op-amp in the unity-gain (1 V/V) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the op-amp output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. When operating in the unity-gain configuration, the OPA2314 device remains stable with a pure capacitive load up to approximately 1 nF. The equivalent series resistance (ESR) of some very large capacitors (C_L greater than 1 μF) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains. See the graph, [Figure 20](#).

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor, typically 10 Ω to 20 Ω , in series with the output, as shown in [Figure 38](#). This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique, however, is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.

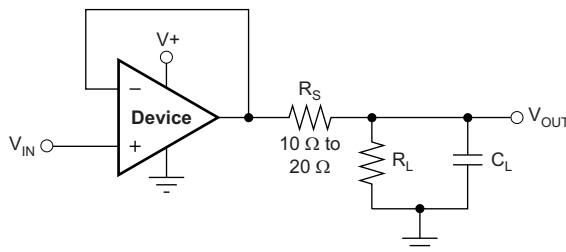


Figure 38. Improving Capacitive Load Drive

8.2 Typical Application

Some applications require differential signals. [Figure 39](#) shows a simple circuit to convert a single-ended input of 0.1 V to 2.4 V into a differential output of ± 2.3 V on a single 2.7-V supply. The output range is intentionally limited to maximize linearity. The circuit is composed of two amplifiers. One amplifier functions as a buffer and creates a voltage, V_{OUT+} . The second amplifier inverts the input and adds a reference voltage to generate V_{OUT-} . Both V_{OUT+} and V_{OUT-} range from 0.1 V to 2.4 V. The difference, V_{DIFF} , is the difference between V_{OUT+} and V_{OUT-} . This makes the differential output voltage range 2.3 V.

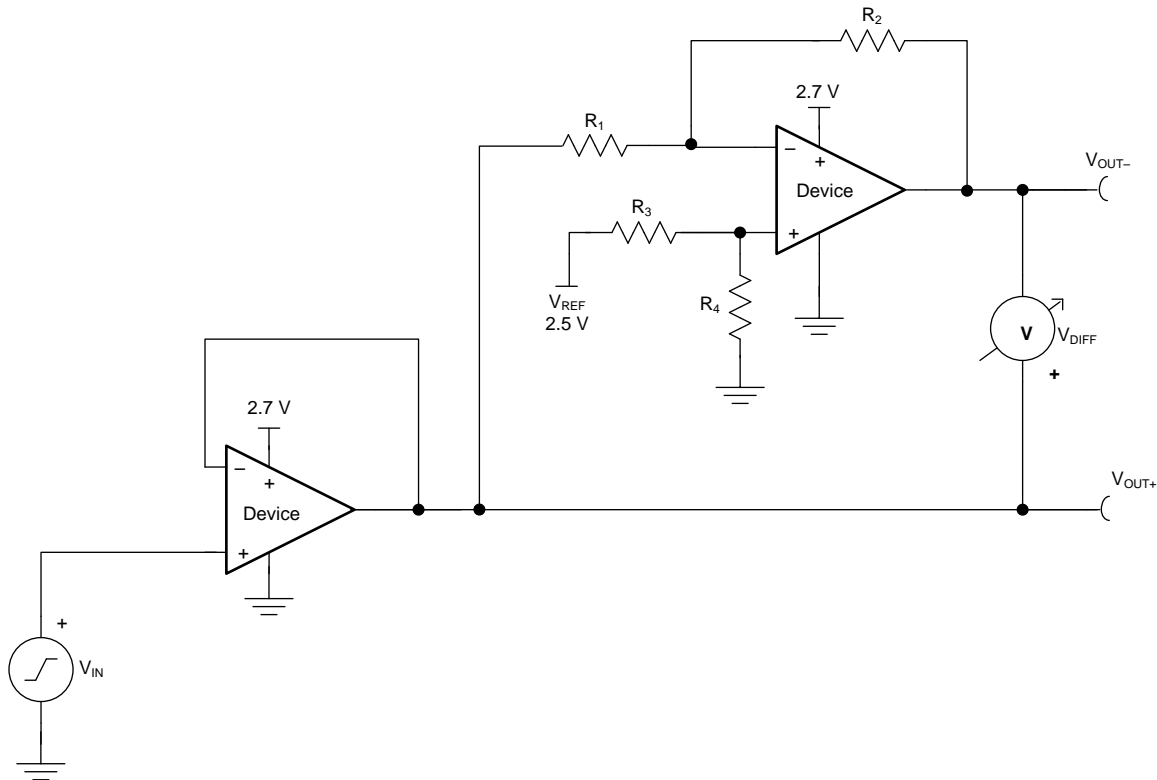


Figure 39. Schematic for a Single-Ended Input to Differential Output Conversion

8.2.1 Design Requirements

The design requirements are as follows:

- Supply voltage: 2.7 V
- Reference voltage: 2.5 V
- Input: 0.1 V to 2.4 V
- Output differential: ± 2.3 V
- Output common-mode voltage: 1.25 V
- Small-signal bandwidth: 1 MHz

8.2.2 Detailed Design Procedure

The circuit in [Figure 39](#) takes a single-ended input signal, V_{IN} , and generates two output signals, V_{OUT+} and V_{OUT-} using two amplifiers and a reference voltage, V_{REF} . V_{OUT+} is the output of the first amplifier and is a buffered version of the input signal, V_{IN} (as shown in [Equation 1](#)). V_{OUT-} is the output of the second amplifier which uses V_{REF} to add an offset voltage to V_{IN} and feedback to add inverting gain. The transfer function for V_{OUT-} is given in [Equation 2](#).

$$V_{OUT+} = V_{IN} \quad (1)$$

$$V_{OUT-} = V_{REF} \times \left(\frac{R_4}{R_3 + R_4} \right) \times \left(1 + \frac{R_2}{R_1} \right) - V_{IN} \times \frac{R_2}{R_1} \quad (2)$$

Typical Application (continued)

The differential output signal, V_{DIFF} , is the difference between the two single-ended output signals, V_{OUT+} and V_{OUT-} . Equation 3 shows the transfer function for V_{DIFF} . By applying the conditions that $R_1 = R_2$ and $R_3 = R_4$, the transfer function is simplified into Equation 6. Using this configuration, the maximum input signal is equal to the reference voltage and the maximum output of each amplifier is equal to V_{REF} . The differential output range is $2 \times V_{REF}$. Furthermore, the common-mode voltage is one half of V_{REF} (see Equation 7).

$$V_{DIFF} = V_{OUT+} - V_{OUT-} = V_{IN} \times \left(1 + \frac{R_2}{R_1}\right) - V_{REF} \times \left(\frac{R_4}{R_3 + R_4}\right) \times \left(1 + \frac{R_2}{R_1}\right) \quad (3)$$

$$V_{OUT+} = V_{IN} \quad (4)$$

$$V_{OUT-} = V_{REF} - V_{IN} \quad (5)$$

$$V_{DIFF} = 2 \times V_{IN} - V_{REF} \quad (6)$$

$$V_{CM} = \left(\frac{V_{OUT+} + V_{OUT-}}{2}\right) = \frac{1}{2} V_{REF} \quad (7)$$

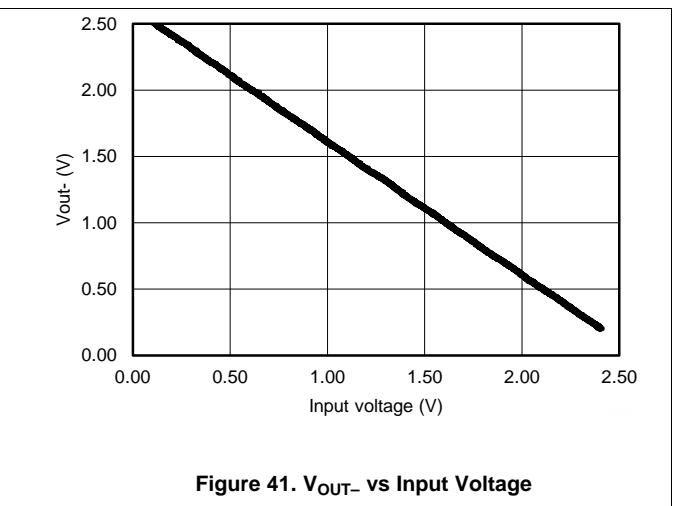
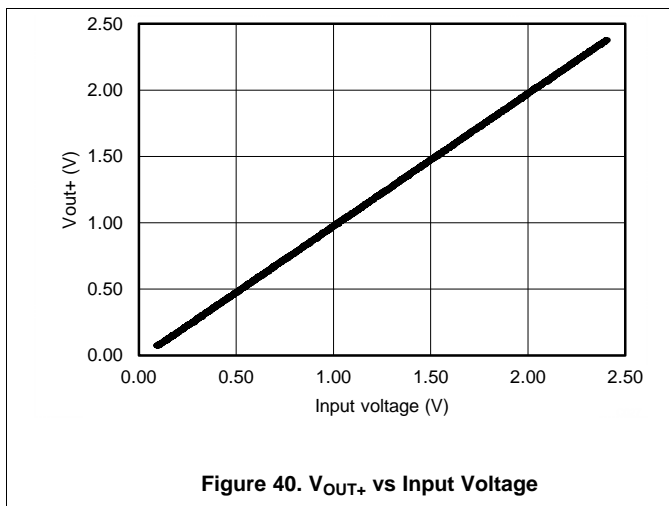
8.2.2.1 Amplifier Selection

Linearity over the input range is key for good dc accuracy. The common-mode input range and output swing limitations determine the linearity. In general, an amplifier with rail-to-rail input and output swing is required. Bandwidth is a key concern for this design, so the OPA2314-Q1 device is selected because its bandwidth is greater than the target of 1 MHz. The bandwidth and power ratio makes this device power efficient and the low offset and drift ensure good accuracy for moderate precision applications.

8.2.2.2 Passive Component Selection

Because the transfer function of V_{out-} is heavily reliant on resistors (R_1 , R_2 , R_3 , and R_4), use resistors with low tolerances to maximize performance and minimize error. This design uses resistors with resistance values of 49.9 k Ω and tolerances of 0.1%. However, if the noise of the system is a key parameter, smaller resistance values (6 k Ω or lower) can be selected to keep the overall system noise low. This ensures that the noise from the resistors is lower than the amplifier noise.

8.2.3 Application Curves



Typical Application (continued)

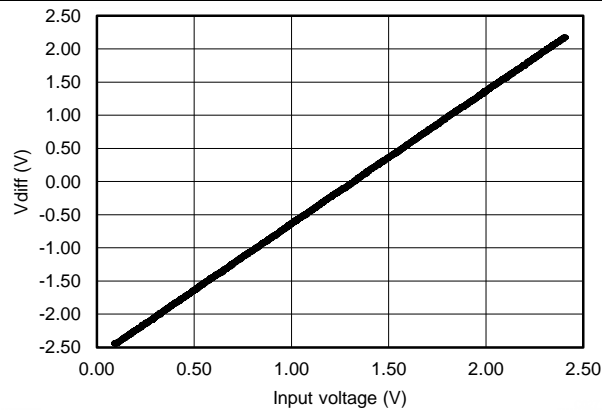


Figure 42. V_{DIFF} vs Input Voltage

9 Power Supply Recommendations

The OPA2314-Q1 device is specified for operation from 1.8 V to 5.5 V (± 0.9 V to ± 2.75 V); many specifications apply from -40°C to 125°C . The [Typical Characteristics](#) presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 7 V can permanently damage the device (see the [Absolute Maximum Ratings](#)).

Place 0.1- μF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, refer to the [Layout Guidelines](#) section.

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1- μ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, refer to *Circuit Board Layout Techniques*, [SLOA089](#).
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better than crossing in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in [Figure 43](#).
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

10.2 Layout Example

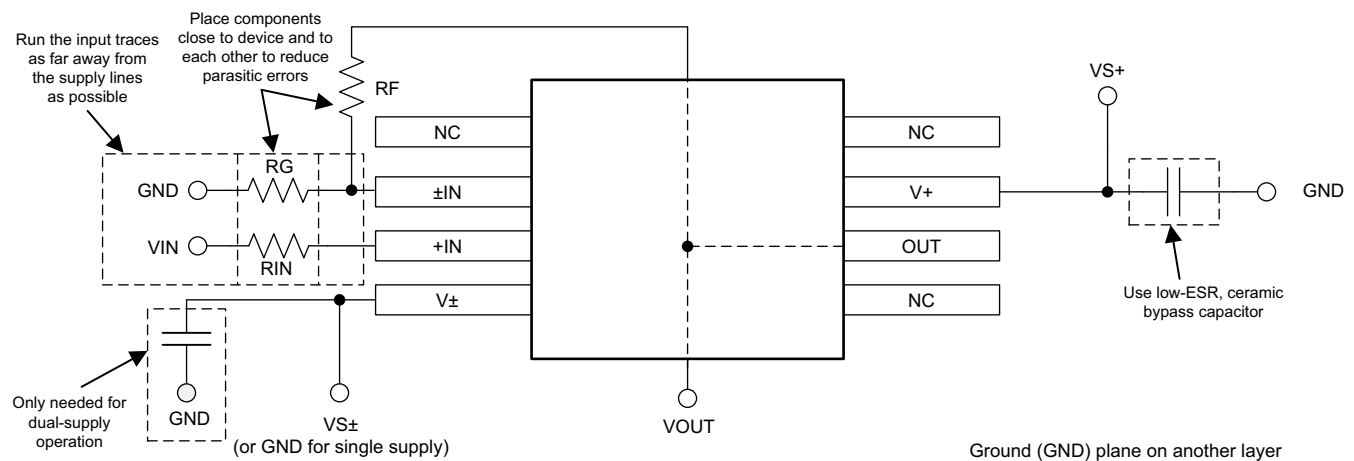
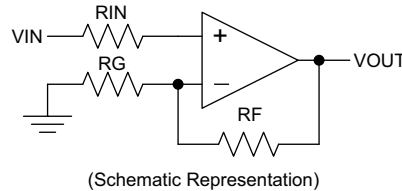


Figure 43. Operational Amplifier Board Layout for Noninverting Configuration

11 器件和文档支持

11.1 器件支持

11.1.1 器件命名规则

11.1.1.1 双边扁平无引线 (DFN) 封装

OPA2314 (双通道版本) 使用 DFN 类型封装 (也称为小外形尺寸无引线 (SON) 封装); 这个封装是只在封装底部两侧有接触点的四方扁平无引线 (QFN) 封装。这个无引线封装大大增加了印刷电路板 (PCB) 尺寸并且通过一个外露散热垫来提高散热和电气特性。DFN 封装的一个主要优势是其 0.9mm 的低高度。DFN 封装物理尺寸小, 具有更小的走线面积、改进的散热性能、减少的电气寄生, 并且使用一个与其它诸如小外形尺寸 (SO) 和微型小外形尺寸 (MSOP) 等常见封装一致的引脚分配机制。此外, 无外部引线也消除了引线弯曲问题的出现。

DFN 封装可使用标准 PCB 组装技巧轻松安装。请参见应用手册《QFN/SO_N PCB 附件》(文献编号: [SLUA271](#)) 和应用报告《四方扁平无引线逻辑封装》(文献编号: [SCBA017](#))。以上文献均可从 [www.ti.com](#) 下载。

注

DFN 封装底部的外露引线框下垫板应该被连接至最低负电压 (V-).

11.2 相关链接

以下表格列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件, 并且可以快速访问样片或购买链接。

表 2. 相关链接

器件	产品文件夹	样片与购买	技术文章	工具与软件	支持与社区
OPA314	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
OPA2314	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
OPA4314	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

11.3 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 商标

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.5 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时, 应将导线一起截短或将装置放置于导电泡棉中, 以防止 MOS 门极遭受静电损伤。

11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2314AID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AID.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDG4	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDG4.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDG4.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OCPQ
OPA2314AIDGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OCPQ
OPA2314AIDGK.B	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OCPQ
OPA2314AIDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU SN NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	OCPQ
OPA2314AIDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OCPQ
OPA2314AIDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
OPA2314AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	O2314
OPA2314AIDRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBR.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBR.B	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBT	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBT.A	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBT.B	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBTG4	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBTG4.A	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA2314AIDRBTG4.B	Active	Production	SON (DRB) 8	250 SMALL T&R	Yes	FULL NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QXY
OPA314AIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA314AIDBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVRG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDBVT.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	RAZ
OPA314AIDCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKR.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKR.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKRG4	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKRG4.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKRG4.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKT	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKT.A	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SAA
OPA314AIDCKT.B	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	SAA
OPA4314AIPW	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4314
OPA4314AIPW.A	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4314
OPA4314AIPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4314
OPA4314AIPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4314
OPA4314AIPWRG4	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4314
OPA4314AIPWRG4.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA4314

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF OPA2314, OPA314, OPA4314 :

- Automotive : [OPA2314-Q1](#), [OPA314-Q1](#), [OPA4314-Q1](#)
- Enhanced Product : [OPA2314-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2314AIDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2314AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2314AIDRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA2314AIDRBT	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA2314AIDRBTG4	SON	DRB	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA314AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA314AIDBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA314AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA314AIDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
OPA314AIDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
OPA314AIDCKRG4	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
OPA314AIDCKT	SC70	DCK	5	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
OPA4314AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA4314AIPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2314AIDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
OPA2314AIDR	SOIC	D	8	2500	353.0	353.0	32.0
OPA2314AIDRBR	SON	DRB	8	3000	367.0	367.0	35.0
OPA2314AIDRBT	SON	DRB	8	250	210.0	185.0	35.0
OPA2314AIDRBTG4	SON	DRB	8	250	210.0	185.0	35.0
OPA314AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA314AIDBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA314AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA314AIDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
OPA314AIDCKR	SC70	DCK	5	3000	180.0	180.0	18.0
OPA314AIDCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0
OPA314AIDCKT	SC70	DCK	5	250	210.0	185.0	35.0
OPA4314AIPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
OPA4314AIPWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
OPA2314AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA2314AID.A	D	SOIC	8	75	506.6	8	3940	4.32
OPA2314AID.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA2314AIDG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA2314AIDG4.A	D	SOIC	8	75	506.6	8	3940	4.32
OPA2314AIDG4.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA2314AIDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA2314AIDGK.A	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA2314AIDGK.B	DGK	VSSOP	8	80	330	6.55	500	2.88
OPA4314AIPW	PW	TSSOP	14	90	530	10.2	3600	3.5
OPA4314AIPW.A	PW	TSSOP	14	90	530	10.2	3600	3.5

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

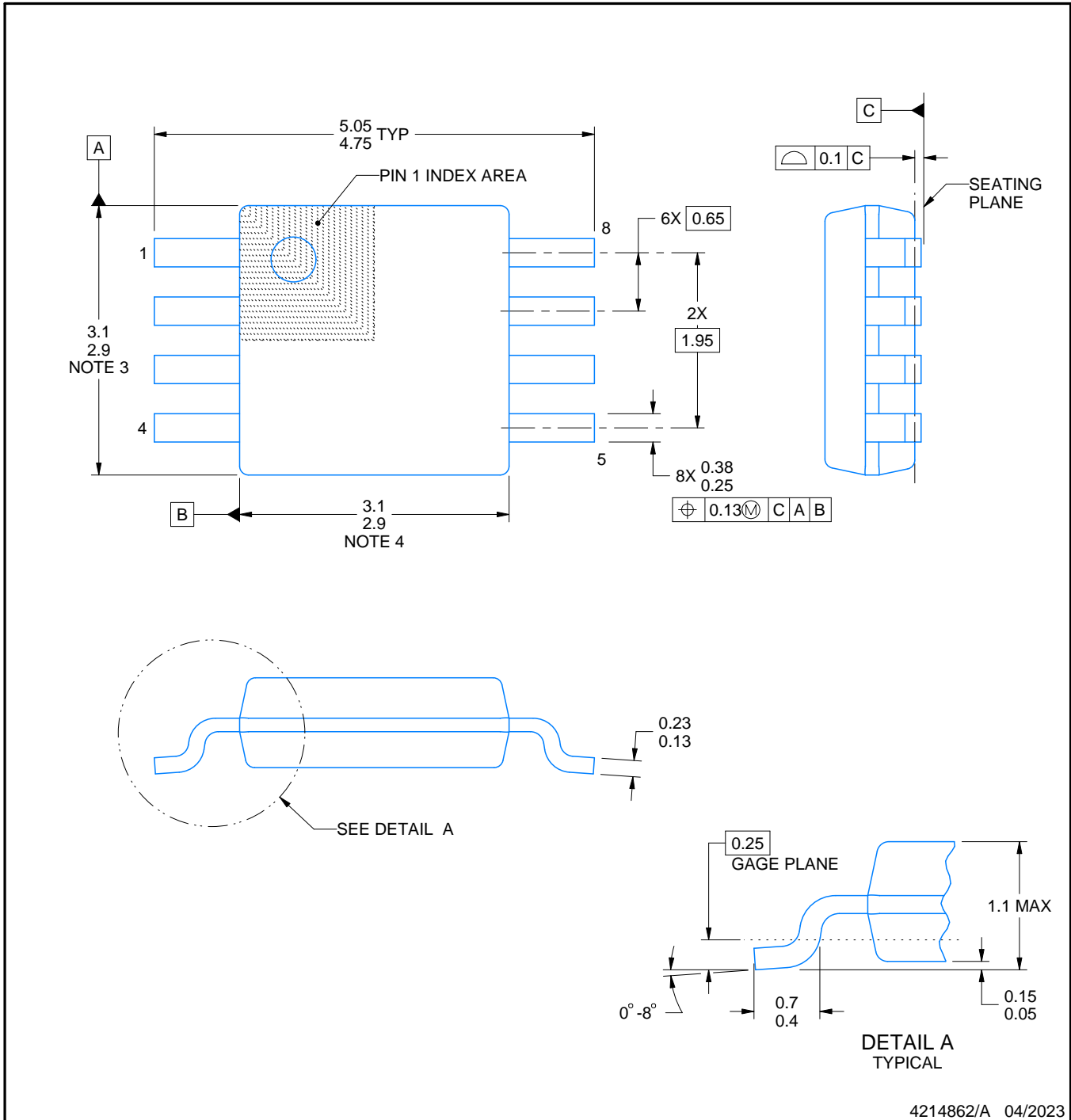
DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

DRB 8

GENERIC PACKAGE VIEW

VSON - 1 mm max height

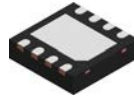
PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203482/L

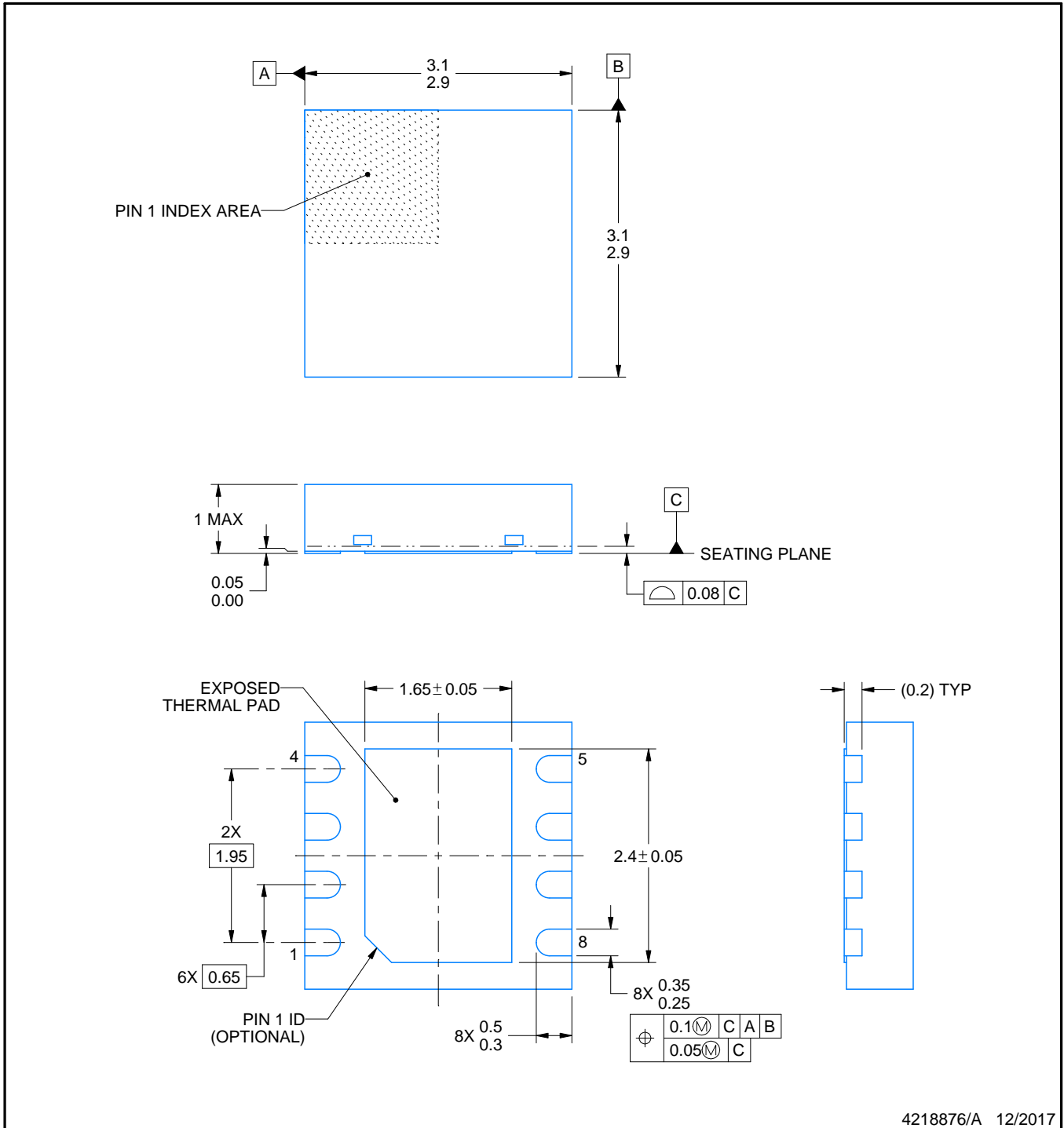
DRB0008B



PACKAGE OUTLINE

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4218876/A 12/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:20X



SOLDER MASK DETAILS

4218876/A 12/2017

NOTES: (continued)

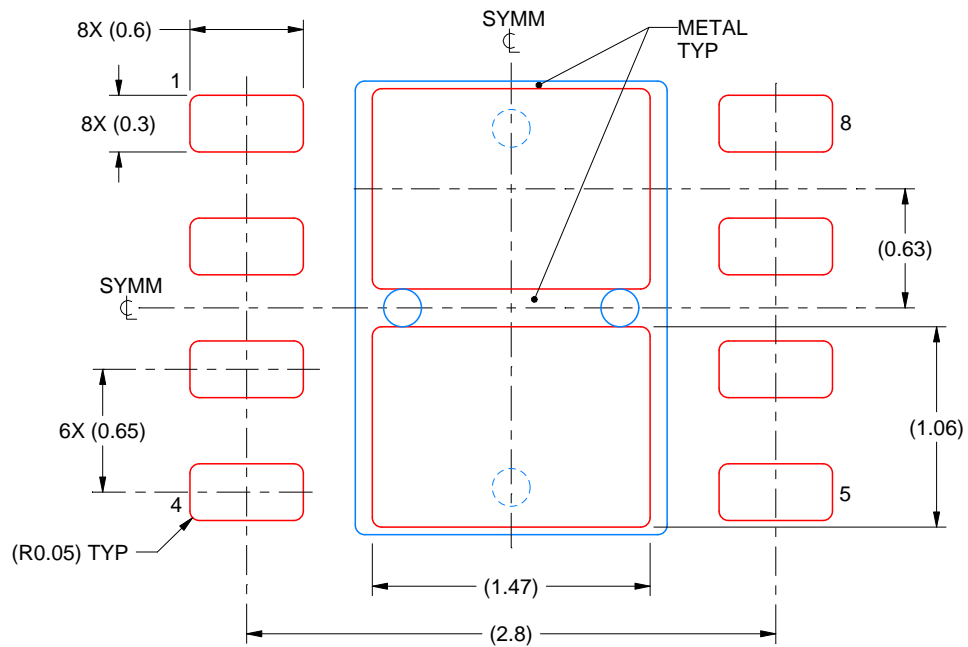
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRB0008B

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
81% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

4218876/A 12/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

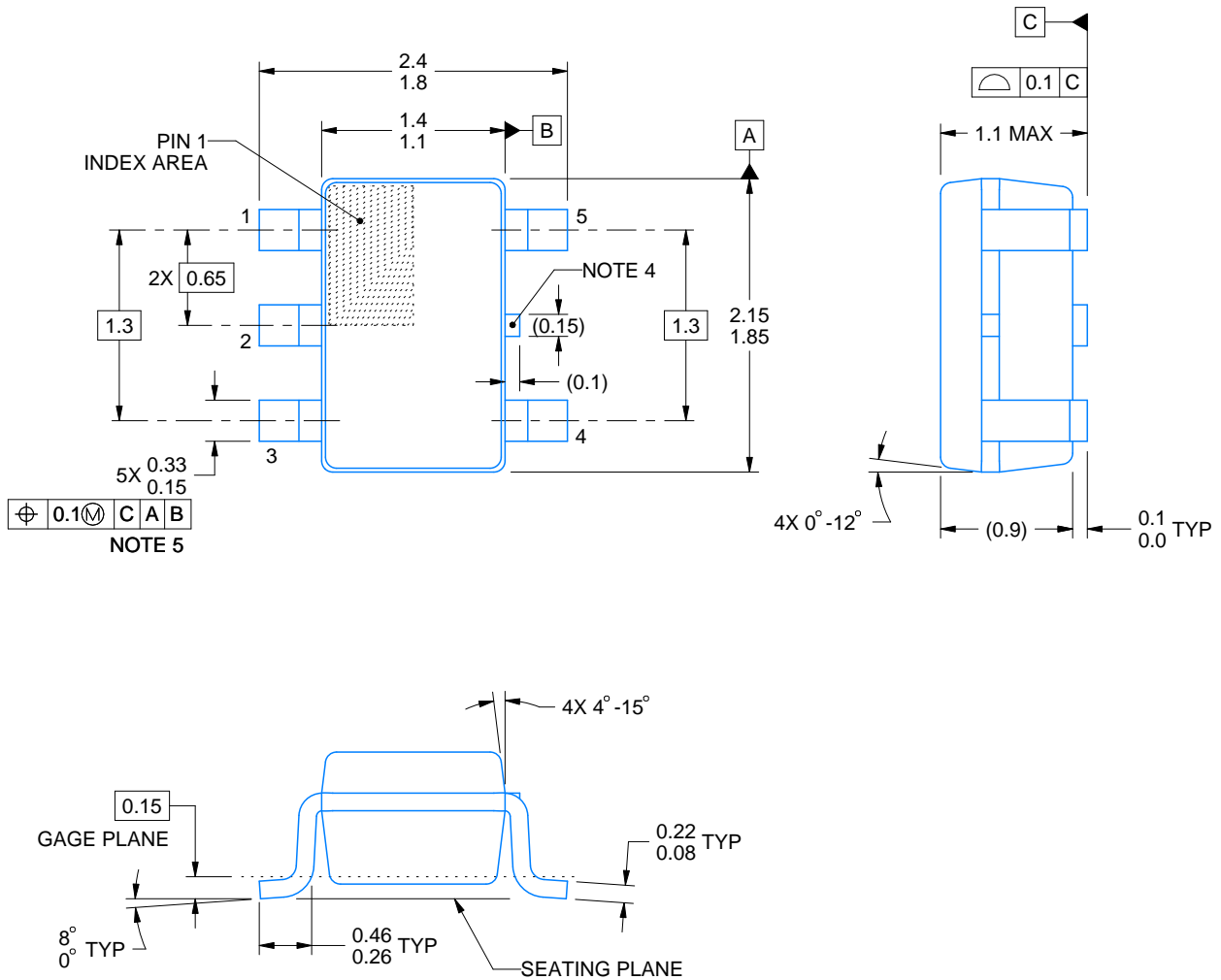
DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

EXAMPLE BOARD LAYOUT

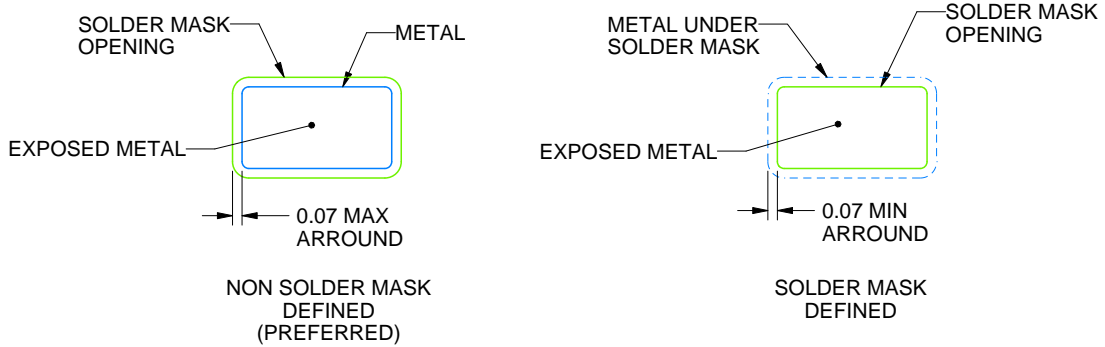
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PW0014A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220202/B 12/2023

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220202/B 12/2023

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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